

IN THE U.S. PATENT AND TRADEMARK OFFICE

COPY

Applicant: HWANG, Lee-Yeun

Application No.:

Group:

Filed: May 24, 2001

Examiner:

For: HIGH VOLTAGE DEVICE HAVING POLYSILICON REGION IN TRENCH AND FABRICATING METHOD THEREOF

L E T T E R

Honorable Commissioner of Patents
and Trademarks
Washington, D.C. 20231

May 24, 2001
0630-1177P

Sir:

Under the provisions of 35 USC 119 and 37 CFR 1.55(a), the applicant hereby claims the right of priority based on the following application(s):

<u>Country</u>	<u>Application No.</u>	<u>Filed</u>
REPUBLIC OF KOREA	43812/2000	07/28/00

A certified copy of the above-noted application(s) is(are) attached hereto.

If necessary, the Commissioner is hereby authorized in this, concurrent, and future replies, to charge payment or credit any overpayment to Deposit Account No. 02-2448 for any additional fees required under 37 C.F.R. 1.16 or under 37 C.F.R. 1.17; particularly, extension of time fees.

Respectfully submitted,

BIRCH, STEWART, KOLASCH & BIRCH, LLP

By:

GARY D. YACURA

Reg. No. 35,416

P. O. Box 747

Falls Church, Virginia 22040-0747

Attachment
(703) 205-8000
/nv

630-1177

"WANG, Lee-Yeun

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(703) 205-8000

BSK&B, LLD

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대한민국 특허청
KOREAN INDUSTRIAL
PROPERTY OFFICE

별첨 사본은 아래 출원의 원본과 동일함을 증명함.

This is to certify that the following application annexed hereto
is a true copy from the records of the Korean Industrial
Property Office.

출원번호 : 특허출원 2000년 제 43812 호
Application Number

출원년월일 : 2000년 07월 28일
Date of Application

출원인 : 현대전자산업주식회사
Applicant(s)

2000 년 09 월 02 일

특허청

COMMISSIONER

